



#### N-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
20V	$25m\Omega @ V_{GS} = 4.5V$	6.5A

## **Features and Benefits**

- Low On-Resistance
- Low-Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMG6968UQ is suitable for automotive applications requiring specific change control and is AEC-Q101 qualified, is PPAP capable, and is manufactured in IATF16949:2016 certified facilities.

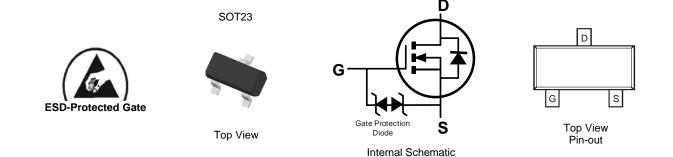
## **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Power-Management Functions
- DC-DC Converters
- Motor Control

#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe.
  Solderable per MIL-STD-202, Method 208 ©3
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)



## Ordering Information (Note 4)

	-		
	Part Number	Case	Packaging
DMG6968UQ-7		SOT23	3000/Tape & Reel
Notes:	1. No purposely added lead. Fully EU Direct	tive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/	863/EU (RoHS 3) compliant.

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 See https://www.alodes.com/quality/lead-free/ for more information about Diodes incorporated s definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 Unlead-free.
 Unlead-free.
 Constraints of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

	Π	
2	N4	ΥM

2N4 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: G = 2019) M = Month (ex: 9 = September)

#### Date Code Key

Year	2019		2020	2021		2022	2023		2024	2025		2026
Code	G		Н			J	K		L	М		N
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characte	eristic		Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	20	V
Gate-Source Voltage		V <sub>GSS</sub>	±12	V	
Continuous Drain Current (Note 5)Steady State $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$			ID	6.5 5.2	A
Pulsed Drain Current			I <sub>DM</sub>	30	А

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	1.3	W
Thermal Resistance, Junction to Ambient @ $T_A = +25^{\circ}C$	R <sub>θJA</sub>	157	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	C

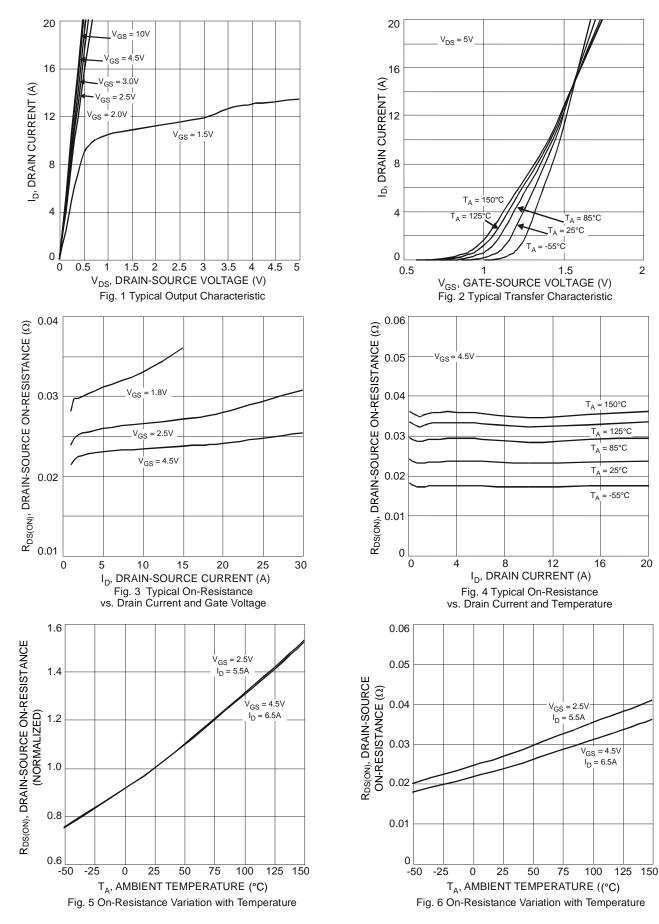
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)	·			•		÷	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	—	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current $T_J = +2$	5°C I <sub>DSS</sub>	_	—	1.0	μA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±10	μΑ	$V_{GS} = \pm 10V, V_{DS} = 0V$	
Gate-Source Breakdown Voltage	BV <sub>GSS</sub>	±12	_	_	V	$V_{DS} = 0V, I_G = \pm 250 \mu A$	
ON CHARACTERISTICS (Note 6)						•	
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.5	_	0.9	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
			21	25		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 6.5A	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	23	29	mΩ	V <sub>GS</sub> = 2.5V, I <sub>D</sub> = 5.5A	
			28	36		V <sub>GS</sub> = 1.8V, I <sub>D</sub> = 3.5A	
Forward Transfer Admittance	Y <sub>fs</sub>		8	_	S	$V_{DS} = 10V, I_{D} = 5A$	
DYNAMIC CHARACTERISTICS (Note 7)	•		•	•		•	
Input Capacitance	C <sub>iss</sub>	_	151	—	pF		
Output Capacitance	C <sub>oss</sub>	_	91	—	pF	$V_{DS} = 10V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	32	_	pF		
Total Gate Charge	Qg	_	8.5	_	nC		
Gate-Source Charge	Q <sub>gs</sub>	_	1.6	_	nC	V <sub>GS</sub> = 4.5V, V <sub>DS</sub> = 10V, I <sub>D</sub> = 6.4	
Gate-Drain Charge	Q <sub>gd</sub>	_	2.8	_	nC		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	54	—	ns		
Turn-On Rise Time	t <sub>R</sub>	—	66	—	ns	V <sub>DD</sub> = 10V, V <sub>GS</sub> = 4.5V,	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	—	613	—	ns	$R_L = 10\Omega, R_G = 6\Omega, I_D = 1A$	
Turn-Off Fall Time	tF	_	205	_	ns		

 Device mounted on 1" × 1" FR-4 PCB with high-coverage 2oz copper, single sided.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing. Notes:

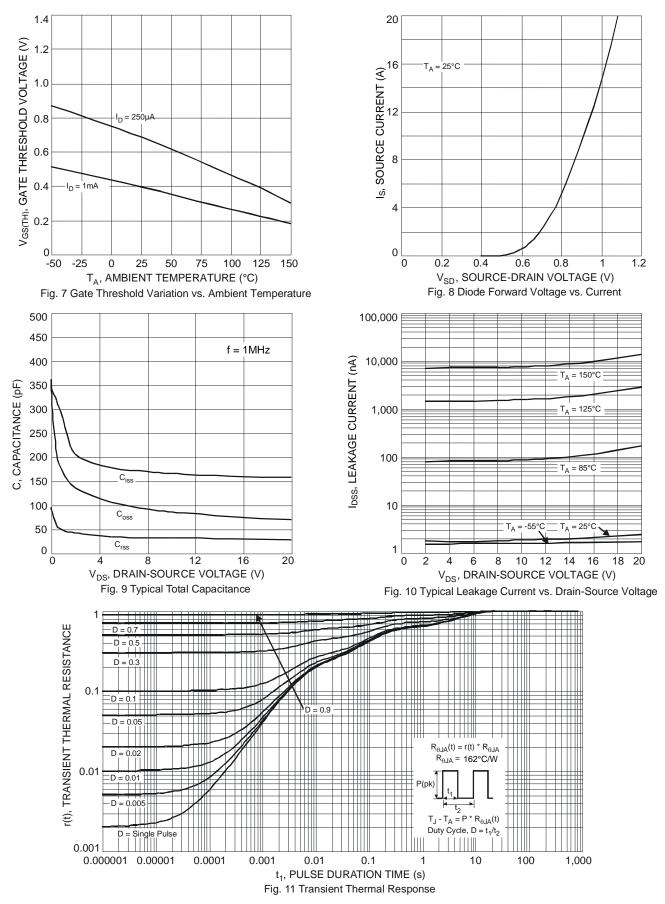


# DMG6968UQ





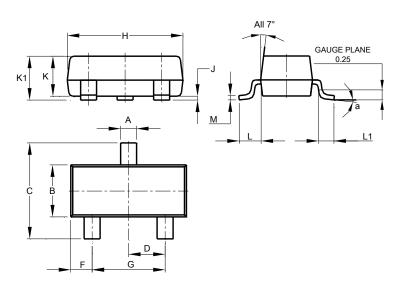
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# **Package Outline Dimensions**

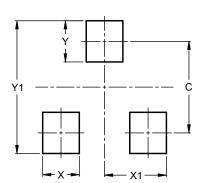
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	Dimens	ions in	mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

SOT23



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